## 1. General description

PNP/PNP matched double transistor in a SOT363 (SC-88) very small Surface-Mounted Device (SMD) plastic package.

### 2. Features and benefits

- Current gain matching
- Base-emitter voltage matching
- Application-optimized pinout

# 3. Applications

- · Current mirror
- Differential amplifier

#### 4. Quick reference data

#### Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit		
Per transistor	Per transistor								
V <sub>CEO</sub>	collector-emitter voltage	open base		-	-	-40	V		
I <sub>C</sub>	collector current			-	-	-200	mA		
h <sub>FE</sub>	DC current gain	$V_{CE}$ = -1 V; $I_{C}$ = -10 mA; $T_{amb}$ = 25 °C		100	180	300			
Per device	Per device								
h <sub>FE1</sub> /h <sub>FE2</sub>	DC current gain matching	$V_{CE} = -5 \text{ V}; I_{C} = -2 \text{ mA}; T_{amb} = 25 \text{ °C}$	[1]	0.95	1	-			
V <sub>BE1</sub> -V <sub>BE2</sub>	base-emitter voltage matching		[2]	-	-	2	mV		

- [1] The smaller of the two values is taken as the numerator.
- [2] The smaller of the two values is subtracted from the larger value.



#### 40 V, 200 mA PNP/PNP matched double transistor

# 5. Pinning information

#### **Table 2. Pinning information**

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	B1	base TR1		04 54 50
2	B2	base TR2	6 5 4	C1 E1 E2
3	C2	collector TR2		TR2
4	E2	emitter TR2		
5	E1	emitter TR1		B1 B2 C2 006aaa550
6	C1	collector TR1	TSSOP6 (SOT363)	

# 6. Ordering information

#### **Table 3. Ordering information**

Type number	Package		
	Name	Description	Version
PMP3906AYS		plastic, surface-mounted package; 6 leads; 0.65 mm pitch; 2.1 mm x 1.25 mm x 0.95 mm body	SOT363

## 7. Marking

#### Table 4. Marking codes

Type number	Marking code[1]
PMP3906AYS	2G%

<sup>[1] % =</sup> placeholder for manufacturing site code

# 8. Limiting values

#### Table 5. Limiting values

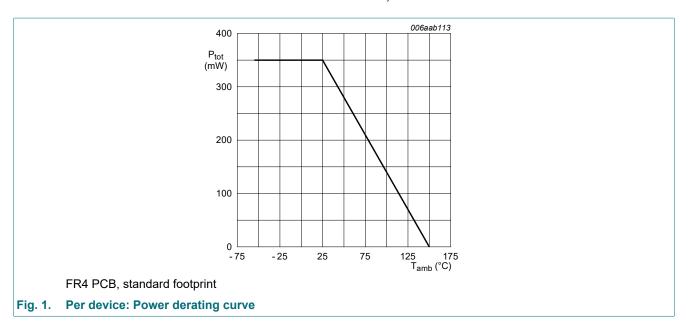
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
Per transist	or		,	'	'	
$V_{CBO}$	collector-base voltage	open emitter		-	-40	V
$V_{CEO}$	collector-emitter voltage	open base		-	-40	V
V <sub>EBO</sub>	emitter-base voltage	open collector		-	-6	V
Ic	collector current			-	-200	mA
I <sub>CM</sub>	peak collector current	single pulse; t <sub>p</sub> ≤ 1 ms		-	-200	mA
I <sub>BM</sub>	peak base current			-	-100	mA
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	[1]	-	230	mW
Per device			•			
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	[1]	-	350	mW
Tj	junction temperature			-	150	°C
T <sub>amb</sub>	ambient temperature			-55	150	°C
T <sub>stg</sub>	storage temperature			-65	150	°C

<sup>[1]</sup> Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

PMP3906AYS

#### 40 V, 200 mA PNP/PNP matched double transistor

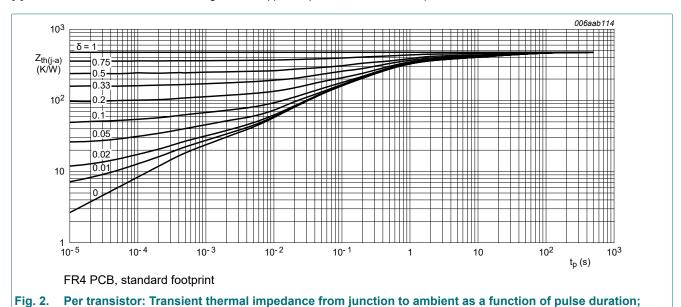


### 9. Thermal characteristics

Table 6. Thermal characteristics

Table 6. Then	illai cilaracteristics			1			
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transisto	or						
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	543	K/W
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point			-	-	290	K/W
Per device	•				'	'	
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	357	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.



typical values

### 40 V, 200 mA PNP/PNP matched double transistor

# 10. Characteristics

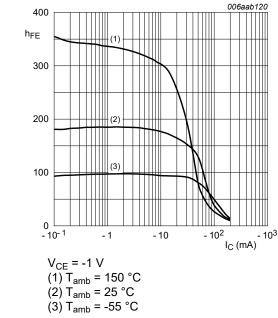
Table 7. Characteristics

Parameter	Conditions		Min	Тур	Max	Unit
or				. 16	ax	O'IIIC
-	L = 400 A. L = 0 A. T = 25 °C		40			1/
breakdown voltage	I <sub>C</sub> = -100 μA; I <sub>E</sub> = 0 A; I <sub>amb</sub> = 25 °C		-40	-	-	V
emitter-base breakdown voltage	$I_C = 0 \text{ A}; I_E = -100 \mu\text{A}; T_{amb} = 25 \text{ °C}$		-6	-	-	V
collector-base cut-off current	$V_{CB} = -32 \text{ V}; I_{E} = 0 \text{ A}; T_{amb} = 25 ^{\circ}\text{C}$		-	-	-50	nA
emitter-base cut-off current	V <sub>EB</sub> = -6 V; I <sub>C</sub> = 0 A; T <sub>amb</sub> = 25 °C		-	-	-50	nA
DC current gain	V <sub>CE</sub> = -1 V; I <sub>C</sub> = -100 μA; T <sub>amb</sub> = 25 °C		60	180	-	
	V <sub>CE</sub> = -1 V; I <sub>C</sub> = -1 mA; T <sub>amb</sub> = 25 °C		80	180	-	
	$V_{CE}$ = -1 V; $I_{C}$ = -10 mA; $T_{amb}$ = 25 °C		100	180	300	
	V <sub>CE</sub> = -1 V; I <sub>C</sub> = -50 mA; T <sub>amb</sub> = 25 °C		60	130	-	
	$V_{CE}$ = -1 V; $I_{C}$ = -100 mA; pulsed; $t_{p} \le$ 300 µs; $T_{amb}$ = 25 °C		30	50	-	
collector-emitter	I <sub>C</sub> = -10 mA; I <sub>B</sub> = -1 mA; T <sub>amb</sub> = 25 °C		-	-	-250	mV
saturation voltage	I <sub>C</sub> = -50 mA; I <sub>B</sub> = -5 mA; T <sub>amb</sub> = 25 °C		-	-	-400	mV
base-emitter saturation	I <sub>C</sub> = -10 mA; I <sub>B</sub> = -1 mA; T <sub>amb</sub> = 25 °C		-	-	-850	mV
voltage	I <sub>C</sub> = -50 mA; I <sub>B</sub> = -5 mA; T <sub>amb</sub> = 25 °C		-	-	-950	mV
delay time	I <sub>C</sub> = -10 mA; I <sub>Bon</sub> = -1 mA; I <sub>Boff</sub> = 1 mA;		-	-	35	ns
rise time	T <sub>amb</sub> = 25 °C		-	-	35	ns
turn-on time			-	-	70	ns
storage time			-	-	225	ns
fall time			-	-	75	ns
turn-off time			-	-	300	ns
collector capacitance	$V_{CB}$ = -5 V; $I_{E}$ = 0 A; $i_{e}$ = 0 A; f = 1 MHz; $T_{amb}$ = 25 °C		-	-	4.5	pF
emitter capacitance	$V_{EB}$ = -0.5 V; $I_{C}$ = 0 A; $i_{c}$ = 0 A; $f$ = 1 MHz; $T_{amb}$ = 25 °C		-	-	10	pF
transition frequency	$V_{CE}$ = -20 V; $I_{C}$ = -10 mA; f = 100 MHz; $T_{amb}$ = 25 °C		250	-	-	MHz
noise figure	$V_{CE}$ = -5 V; $I_{C}$ = -100 $\mu$ A; $R_{S}$ = 1 k $\Omega$ ; f = 1 kHz; B = 10 to 15700 Hz; $T_{amb}$ = 25 °C		-	-	4	dB
				,		,
DC current gain matching	$V_{CE}$ = -5 V; $I_{C}$ = -2 mA; $T_{amb}$ = 25 °C	[1]	0.95	1	-	
base-emitter voltage matching		[2]	-	-	2	mV
	collector-base breakdown voltage emitter-base breakdown voltage collector-base cut-off current emitter-base cut-off current DC current gain  collector-emitter saturation voltage base-emitter saturation voltage delay time rise time turn-on time storage time fall time turn-off time collector capacitance emitter capacitance transition frequency noise figure  DC current gain matching base-emitter voltage		$ \begin{array}{c} \text{collector-base} \\ \text{breakdown voltage} \\ \text{emitter-base} \\ \text{breakdown voltage} \\ \text{emitter-base} \\ \text{breakdown voltage} \\ \text{collector-base cut-off} \\ \text{current} \\ \text{emitter-base cut-off} \\ \text{current} \\ \text{emitter-base cut-off} \\ \text{current} \\ \text{DC current gain} \\ \text{DC current gain} \\ \text{V}_{CB} = -6 \text{ V; } \text{ I}_{C} = 0 \text{ A; } \text{ T}_{amb} = 25 \text{ °C} \\ \text{V}_{CE} = -1 \text{ V; } \text{ I}_{C} = -100 \text{ µA; } \text{ T}_{amb} = 25 \text{ °C} \\ \text{V}_{CE} = -1 \text{ V; } \text{ I}_{C} = -100 \text{ µA; } \text{ T}_{amb} = 25 \text{ °C} \\ \text{V}_{CE} = -1 \text{ V; } \text{ I}_{C} = -100 \text{ µA; } \text{ T}_{amb} = 25 \text{ °C} \\ \text{V}_{CE} = -1 \text{ V; } \text{ I}_{C} = -100 \text{ mA; } \text{ T}_{amb} = 25 \text{ °C} \\ \text{V}_{CE} = -1 \text{ V; } \text{ I}_{C} = -100 \text{ mA; } \text{ T}_{amb} = 25 \text{ °C} \\ \text{V}_{CE} = -1 \text{ V; } \text{ I}_{C} = -100 \text{ mA; } \text{ T}_{amb} = 25 \text{ °C} \\ \text{V}_{CE} = -1 \text{ V; } \text{ I}_{C} = -100 \text{ mA; } \text{ T}_{amb} = 25 \text{ °C} \\ \text{V}_{CE} = -1 \text{ V; } \text{ I}_{C} = -100 \text{ mA; } \text{ T}_{amb} = 25 \text{ °C} \\ \text{V}_{CE} = -1 \text{ V; } \text{ I}_{C} = -100 \text{ mA; } \text{ T}_{amb} = 25 \text{ °C} \\ \text{V}_{CE} = -10 \text{ mA; } \text{ I}_{B} = -1 \text{ mA; } \text{ T}_{amb} = 25 \text{ °C} \\ \text{I}_{C} = -50 \text{ mA; } \text{ I}_{B} = -5 \text{ mA; } \text{ T}_{amb} = 25 \text{ °C} \\ \text{I}_{C} = -50 \text{ mA; } \text{ I}_{B} = -5 \text{ mA; } \text{ T}_{amb} = 25 \text{ °C} \\ \text{I}_{C} = -50 \text{ mA; } \text{ I}_{B} = -5 \text{ mA; } \text{ T}_{amb} = 25 \text{ °C} \\ \text{I}_{C} = -50 \text{ mA; } \text{ I}_{B} = -5 \text{ mA; } \text{ T}_{amb} = 25 \text{ °C} \\ \text{I}_{C} = -10 \text{ mA; } \text{ I}_{B} = -1 \text{ mA; } \text{ I}_{B} = 1 \text{ mA; } \text{ I}_{B} = 25 \text{ °C} \\ \text{I}_{C} = -10 \text{ mA; } \text{ I}_{B} = -1 \text{ mA; } \text{ I}_{B} = 1 \text{ mA; } \text{ I}_{B} = 1 \text{ mA; } \text{ I}_{B} = 25 \text{ °C} \\ \text{I}_{C} = -10 \text{ mA; } \text{ I}_{B} = -1 \text{ mA; } \text{ I}_{B} = 1 \text{ mA; } \text{ I}_{B} = 25 \text{ °C} \\ \text{I}_{C} = -10 \text{ mA; } \text{ I}_{B} = -1 \text{ mA; } \text{ I}_{B} = 25 \text{ °C} \\ \text{I}_{C} = -10 \text{ mA; } \text{ I}_{B} = -1 \text{ mA; } \text{ I}_{B} = 1 \text{ mA; } \text{ I}_{B} = 25 \text{ °C} \\ \text{I}_{C} = -10 \text{ mA; } \text{ I}_{B} = -1 \text{ mA; } \text{ I}_{C} = -10 \text{ mA; } \text{ I}_{C} = $	$ \begin{array}{c c c c c c c c c c c c c c c c c c c $	collector-base breakdown voltage $I_C = -100 \ \mu A; \ I_E = 0 \ A; \ T_{amb} = 25 \ ^{\circ}C$ -40         -           emitter-base breakdown voltage $I_C = 0 \ A; \ I_E = -100 \ \mu A; \ T_{amb} = 25 \ ^{\circ}C$ -6         -           collector-base cut-off current $V_{CB} = -32 \ V; \ I_E = 0 \ A; \ T_{amb} = 25 \ ^{\circ}C$ -         -           emitter-base cut-off current $V_{CB} = -32 \ V; \ I_C = 0 \ A; \ T_{amb} = 25 \ ^{\circ}C$ -         -           DC current gain $V_{CB} = -1 \ V; \ I_C = -100 \ \mu A; \ T_{amb} = 25 \ ^{\circ}C$ 80         180           VCE = -1 V; \ I_C = -10 \ mA; \ T_{amb} = 25 \ ^{\circ}C         80         180           VCE = -1 V; \ I_C = -10 \ mA; \ T_{amb} = 25 \ ^{\circ}C         100         180           VCE = -1 V; \ I_C = -10 \ mA; \ T_{amb} = 25 \ ^{\circ}C         60         130           VCE = -1 V; \ I_C = -10 \ mA; \ T_{amb} = 25 \ ^{\circ}C         -         -           collector-emitter saturation voltage         IC = -10 \ mA; \ I_B = -1 \ mA; \ T_{amb} = 25 \ ^{\circ}C         -         -           base-emitter saturation voltage         IC = -50 \ mA; \ I_B = -5 \ mA; \ T_{amb} = 25 \ ^{\circ}C         -         -           delay time         IC = -50 \ mA; \ I_B = -1 \ mA; \ T_{amb} = 25 \ ^{\circ}C         -         -           delay time         IC = -10 \ mA; \ I_B = -1 \ mA; \ I_B = 0 \ mA; \ I_B = 1 \ mA	Collector-base breakdown voltage   Ic = -100 μA; I <sub>E</sub> = 0 A; T <sub>amb</sub> = 25 °C   -6   -6   -6   -6   -6   -6   -6   -

<sup>[1]</sup> The smaller of the two values is taken as the numerator.

<sup>[2]</sup> The smaller of the two values is subtracted from the larger value.

#### 40 V, 200 mA PNP/PNP matched double transistor



$$V_{CE} = -1 V$$

(3) 
$$T_{amb} = -55 \, ^{\circ}C$$

Fig. 3. DC current gain as a function of collector current; typical values

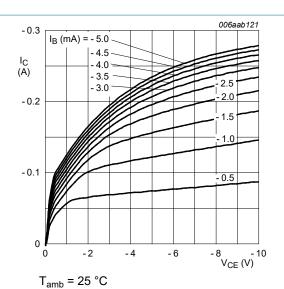
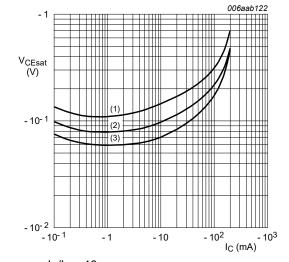


Fig. 4. Collector current as a function of collectoremitter voltage; typical values



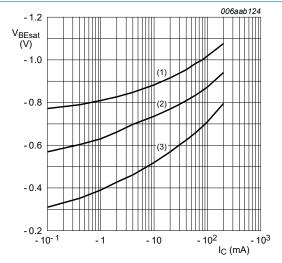
 $I_{\rm C}/I_{\rm B}=10$ 

$$(1) T_{amb} = 150 °($$

(1) 
$$T_{amb} = 150 \,^{\circ}C$$
  
(2)  $T_{amb} = 25 \,^{\circ}C$ 

(3) 
$$T_{amb} = -55 \, ^{\circ}C$$

Fig. 5. Collector-emitter saturation voltage as a function of collector current; typical values



$$I_{\rm C}/I_{\rm B} = 10$$

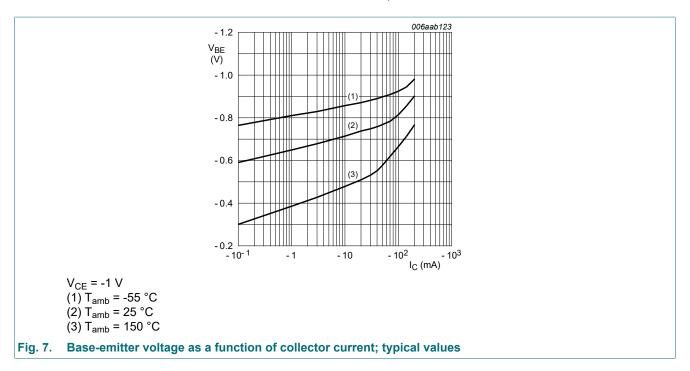
(1) 
$$T_{amb} = -55 \, ^{\circ}C$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

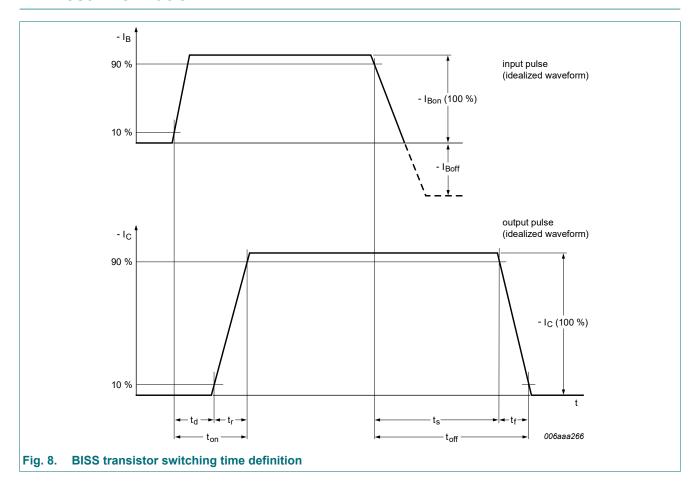
$$(3) T_{amb} = 100 °C$$

Fig. 6. Base-emitter saturation voltage as a function of collector current; typical values

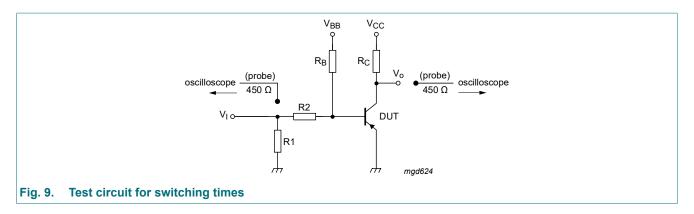
#### 40 V, 200 mA PNP/PNP matched double transistor



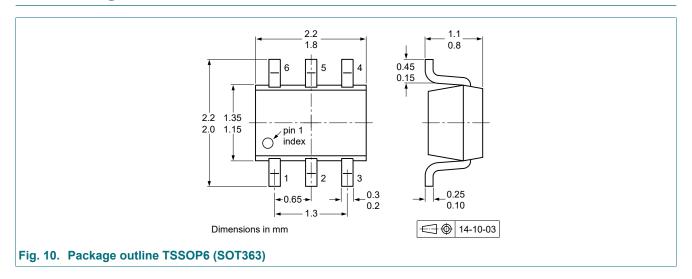
## 11. Test information



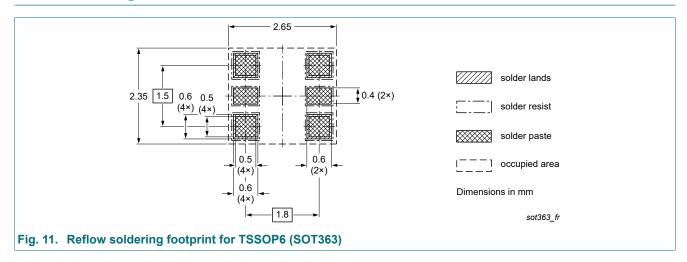
#### 40 V, 200 mA PNP/PNP matched double transistor



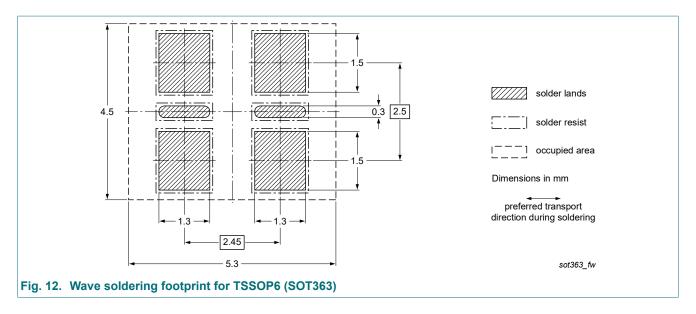
# 12. Package outline



# 13. Soldering



### 40 V, 200 mA PNP/PNP matched double transistor



### 40 V, 200 mA PNP/PNP matched double transistor

# 14. Revision history

#### **Table 8. Revision history**

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PMP3906AYS v.1	20220727	Product data sheet	-	-

## 15. Legal information

#### **Data sheet status**

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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For more information, please visit: http://www.nexperia.com For sales office addresses, please send an email to: salesaddresses@nexperia.com Date of release: 27 July 2022

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